

TOSHIBA PHOTOCOUPLER GaAs IRED & PHOTO-TRIAC

TLP666J

OFFICE MACHINE

HOUSEHOLD USE EQUIPMENT

TRIAC DRIVER

SOLID STATE RELAY

The TOSHIBA TLP666J consists of a zero voltage crossing turn-on photo-triac optically coupled to a gallium arsenide infrared emitting diode in a six lead plastic DIP.

- Peak Off-State Voltage : 600V (Min.)
- Trigger LED Current : 10mA (Max.)
- On-State Current : 100mA (Max.)
- UL Recognized : UL1577, File No. E67349
- Isolation Voltage : 5000V_{rms} (Min.)
- Option (D4) Type VDE Approved : DIN VDE0884 / 08.87, Certificate No. 68383

Maximum Operating Insulation Voltage : 630V_{PK}Highest Permissible Over Voltage : 6000V_{PK}

(Note 1) When a VDE0884 approved type is needed, please designate the "Option (D4)"

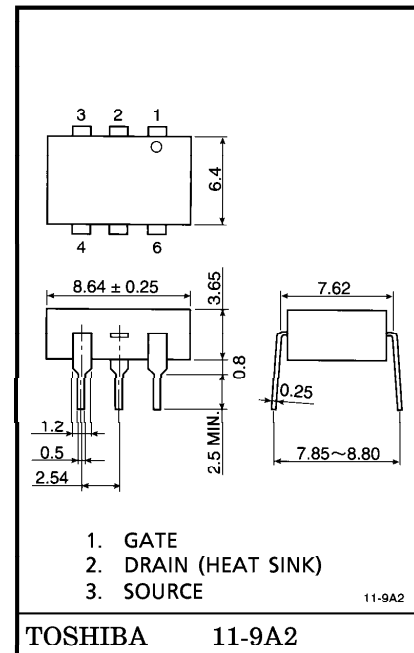
- Structural Parameter

Creepage Distance : 7.0mm (Min.)

Clearance : 7.0mm (Min.)

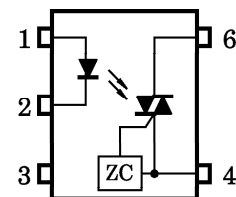
Insulation Thickness : 0.5mm (Min.)

Unit in mm



Weight : 0.44g

PIN CONFIGURATIONS (Top view)



1 : ANODE

2 : CATHODE

3 : N.C.

4 : TERMINAL 1

6 : TERMINAL 2

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MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
LED	Forward Current	I_F	50	mA
	Forward Current Derating (Ta ≤ 53°C)	$\Delta I_F / ^\circ\text{C}$	-0.7	mA / °C
	Peak Forward Current (100μs Pulse, 100pps)	I_{FP}	1	A
	Reverse Voltage	V_R	5	V
	Junction Temperature	T_j	125	°C
DETECTOR	Off-State Output Terminal Voltage	V_{DRM}	600	V
	On-State RMS Current	I_T (RMS)	100	mA
			50	
	On-State Current Derating (Ta ≥ 25°C)	$\Delta I_T / ^\circ\text{C}$	-1.1	mA / °C
	Peak On-State Current (100μs Pulse, 120pps)	I_{TP}	2	A
	Peak Nonrepetitive Surge Current (PW = 10ms, DC = 10%)	I_{TSM}	1.2	A
	Junction Temperature	T_j	115	°C
Storage Temperature Range		T_{stg}	-55~125	°C
Operating Temperature Range		T_{opr}	-40~100	°C
Lead Soldering Temperature (10s)		T_{sol}	260	°C
Isolation Voltage (AC, 1 min., R.H. ≤ 60%) (Note 2)		BVS	5000	V_{rms}

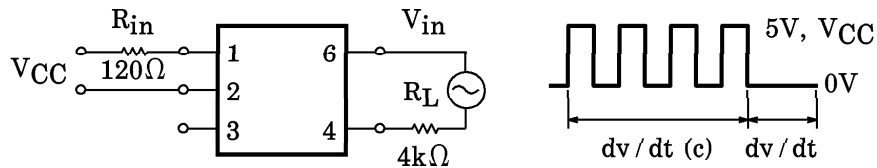
(Note 2) Pins 1, 2 and 3 shorted together pin 4 and 6 shorted together.

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V_{AC}	—	—	240	Vac
Forward Current	I_F	15	20	25	mA
Peak On-Stage Current	I_{TP}	—	—	1	A
Operating Temperature	T_{opr}	-25	—	85	°C

INDIVIDUAL ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
LED	Forward Voltage	V_F	$I_F = 10\text{mA}$	1.0	1.15	1.3	V
	Reverse Current	I_R	$V_R = 5\text{V}$	—	—	10	μA
	Capacitance	C_T	$V = 0, f = 1\text{MHz}$	—	30	—	pF
DETECTOR	Peak Off-State Current	I_{DRM}	$V_{\text{DRM}} = 600\text{V}$	—	10	1000	nA
	Peak On-State Voltage	V_{TM}	$I_{\text{TM}} = 100\text{mA}$	—	1.7	3.0	V
	Holding Current	I_H	—	—	0.6	—	mA
	Critical Rate of Rise of Off-State Voltage	dv/dt	$V_{\text{in}} = 240\text{V}, T_a = 85^\circ\text{C}$ (Note 3)	200	500	—	$\text{V} / \mu\text{s}$
	Critical Rate of Rise of Commutating Voltage	$dv/dt(c)$	$V_{\text{in}} = 60\text{V}_{\text{rms}}, I_T = 15\text{mA}$ (Note 3)	—	0.2	—	$\text{V} / \mu\text{s}$

(Note 3) dv/dt TEST CIRCUIT

COUPLED ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Trigger LED Current	I_{FT}	$V_T = 6\text{V}$	—	5	10	mA
Inhibited Voltage	V_{IH}	$I_F = \text{Rated } I_{\text{FT}}$	—	—	50	V
Leakage in Inhibited State	I_{IH}	$I_F = \text{Rated } I_{\text{FT}}$ $V_T = \text{Rated } V_{\text{DRM}}$	—	200	600	μA
Capacitance (Input to Output)	C_S	$V_S = 0, f = 1\text{MHz}$	—	0.8	—	pF
Isolation Resistance	R_S	$V_S = 500\text{V}, \text{R.H.} \leq 60\%$	1×10^{12}	10^{14}	—	Ω
Isolation Voltage	BV_S	AC, 1 minute	5000	—	—	V_{rms}
		AC, 1 second, in oil	—	10000	—	
		DC, 1 minute, in oil	—	10000	—	Vdc

